

Controlling the microscopic quantum pathways for ultrafast charge transfer in van der Waals heterostructures

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Abstract

Efficient charge separation in van der Waals (vdW) heterostructures is crucial for optimizing light-harvesting and detection applications. However, precise control over the microscopic pathways governing ultrafast charge transfer remains an open challenge. These pathways are intrinsically linked to charge transfer states with strongly delocalized wave functions that appear at various momenta in the Brillouin zone. Here, we use time- and angle-resolved photoemission spectroscopy (trARPES) to investigate the possibility of steering carriers through specific charge transfer states in a prototypical WS₂-graphene heterostructure. By selectively exciting electron-hole pairs at the K-point and close to the Q-point of WS₂ with different pump photon energies, we find that charge separation is faster at higher excitation energies. We attribute this to distinct tunneling mechanisms dictated by the momentum where the initial excitation takes place. Our findings introduce a novel strategy for controlling charge transfer dynamics in vdW heterostructures, paving the way for more efficient optoelectronic devices.

Teaser

Steering ultrafast charge transfer in vdW heterostructures unlocks new paths for efficient light-harvesting and detection devices.

MAIN TEXT

Introduction

The vast selection of 2D materials available today, such as graphene and monolayer transition metal dichalcogenides, enables the design of novel heterostructures with tailored properties [1–3]. Efficient absorption of visible light followed by ultrafast charge separation [4–10] is a key feature of these heterostructures, offering great potential for applications in light harvesting and detection. The driving force behind ultrafast charge separation is the band alignment, where photoexcited electrons and holes rapidly relax to the conduction band minimum and valence band maximum in separate layers. Charge transfer states, formed by hybridization between the vdW-coupled layers, create delocalized wave functions that serve as ultrafast tunnelling channels [11–13]. These states occur at various momenta in the Brillouin zone but do not contribute equally to charge separation. Based on existing models [11, 13–18], the efficiency of different tunnelling channels depends on the orbital composition of charge transfer states, their momentum-space distribution, and tunnelling barriers that photoexcited carriers must overcome. Consequently, it should be possible to steer quantum pathways by selectively generating electron-hole pairs at specific momenta.

Here, we explore this concept in a prototypical vdW heterostructure consisting of monolayer WS₂ and graphene. We photoexcite the heterostructure with pump photon energies of $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$ to excite electron-hole pairs at the K-point and in between the Γ - and Q-point (also referred to as Σ - or Λ -point) of WS₂, respectively, and probe the charge transfer dynamics directly in the band structure using time- and angle-resolved photoemission spectroscopy (trARPES) [19]. We find that charge separation is significantly faster for $\hbar\omega_{pump} = 3.1\text{eV}$, which we attribute to distinct quantum pathways for hole tunneling at different momenta in the Brillouin zone. Our findings introduce new possibilities for optimizing charge separation in vdW heterostructures, paving the way for more efficient light-harvesting and detection technologies.

Results

Figure 1a shows an ARPES image of the WS₂-graphene heterostructure at negative pump-probe delay before the arrival of the pump pulse. The dotted, dashed, and continuous lines indicate the theoretical band structures of WS₂ islands with a twist angle of 0°, WS₂ islands with a twist angle of 30° [20] and graphene [21], respectively. The bands are shifted in energy to fit the experimentally observed band alignment and doping level. Orange and blue arrows mark the electronic transitions excited at $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$, respectively, in WS₂. Here, we will only consider WS₂ islands with 0° twist angle. The influence of the twist angle on ultrafast charge separation will be investigated in a separate work.

Figure 1b depicts the pump-induced changes of the photocurrent in Fig. 1a 240fs after photoexcitation at $\hbar\omega_{pump} = 2.0\text{eV}$ with a fluence of $F = 1.7\text{mJ}/\text{cm}^2$. Brown and blue colors indicate a gain and loss of photoelectrons, respectively, with respect to negative pump-probe delay. Figure 1c is the same as Fig. 1b but for photoexcitation at $\hbar\omega_{pump} = 3.1\text{eV}$ with a fluence of $F = 0.4\text{mJ}/\text{cm}^2$ and 310fs after photoexcitation. For both excitation energies we observe gain in the conduction band (CB) of WS₂, gain (loss) above (below) the equilibrium Fermi level in graphene, and a complex gain-loss signal in the WS₂ valence band (VB) with contributions from band shifts and broadening as previously discussed in [18, 13].

To gain access to the transient carrier population of different areas in the band structure, we integrate the photocurrent over the areas marked by the colored boxes in Figs. 1b and c. The

corresponding pump-probe traces are shown in Fig. 2 together with single-exponential fits yielding the decay times τ . Dashed vertical lines in Fig. 2 indicate the pump-probe delay t_{max} where the respective pump-probe trace reaches its maximum. The fit results are summarized in Table 1. The charge carrier dynamics inside the Dirac cone (Fig. 2a) are found to be quite similar for $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$, respectively, considering that the pump pulses (grey-shaded areas in Fig. 2) were slightly longer for $\hbar\omega_{pump} = 3.1\text{eV}$ than for $\hbar\omega_{pump} = 2.0\text{eV}$. The population dynamics of the WS₂ bands, however, show important differences when comparing the two excitation energies. We find that the gain above the equilibrium position of the WS₂ VB (Fig. 2b) reaches its maximum $\sim 250\text{fs}$ later for $\hbar\omega_{pump} = 2.0\text{eV}$ than for $\hbar\omega_{pump} = 3.1\text{eV}$. Further, for $\hbar\omega_{pump} = 2.0\text{eV}$ the pump-probe signal of the WS₂ CB at K is much bigger than close to Q, indicating that the photoexcited electrons are mainly confined to the K valley (Fig. 3b1). For $\hbar\omega_{pump} = 3.1\text{eV}$, however, we find that the population of the WS₂ CB at K is smaller than the one close to Q and reaches its maximum $\sim 130\text{fs}$ later (Fig. 3b2).

To gain direct access to the timescales for ultrafast charge separation, we extract the related charging-induced band shifts of the WS₂ VB and CB as follows [18, 13]. First, we extract energy distribution curves (EDCs) at $k = 1.2\text{\AA}^{-1}$ from the trAPRES snapshots in Fig. 1 that we fit with an appropriate number of Gaussian peaks to obtain the transient binding energies shown in Fig. 3a. Next, we subtract the transient position of the WS₂ VB from the transient position of the WS₂ CB yielding the transient band gap E_{gap} shown in Fig. 3b. Finally, assuming that the band gap changes symmetrically around its center, we add (subtract) $E_{gap}/2$ to (from) the transient position of the WS₂ VB (CB) to obtain the shifts $\Delta E_{charge}^{WS_2}$ in Fig. 3c that we previously attributed to a transient charging of the WS₂ layer with excess electrons [18, 13]. The corresponding charging shift of the graphene layer in Fig. 3d is obtained by extracting momentum distribution curves (MDCs) in the energy range between 0.2eV and 1.0eV that we fit with a Lorentzian. The resulting peak positions are then multiplied with the slope of the Dirac cone to yield the data points in Fig. 3d. All orange and blue curves in Fig. 3 are single-exponential fits, the fit parameters of which are summarized in Table 2. Vertical dashed orange and blue lines indicate the positions t_{max} , where the respective pump-probe signals reach their maximum. Note that the fit for the transient band gap in Fig. 3b is sensitive to the value assumed for the equilibrium gap size (we assumed 2.08eV) which also affects $\Delta E_{charge}^{WS_2}$ in Fig. 3c. We would like to stress, though, that varying the equilibrium gap size by a reasonable amount has only a minor influence on the data points in Fig. 3c. Considering this, the behavior of the transient WS₂ band gap at $k = 1.2\text{\AA}^{-1}$ is very similar for $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$. In contrast to this, both the WS₂ and the graphene charging shifts are found to depend on the pump photon energy. We find that both charging shifts reach their maximum 160 – 340fs later for $\hbar\omega_{pump} = 2.0\text{eV}$ than for $\hbar\omega_{pump} = 3.1\text{eV}$.

Discussion

The results obtained for $\hbar\omega_{pump} = 2.0\text{eV}$ are in good agreement with previous trARPES results [22, 18, 13] making their interpretation straight forward. The asymmetric population dynamics of the Dirac cone (Fig. 2a1), the gain above the equilibrium position of the WS₂ VB (Fig. 2b1) and the charging shifts in Figs. 3c and d provide direct evidence of ultrafast charge separation in the WS₂-graphene heterostructure, where hole transfer from WS₂ to graphene is much faster than electron transfer. The transient reduction of the band gap in Fig. 3b has been previously attributed to screening of the Coulomb interaction by photoinduced free carriers [23–29].

The observed differences between excitation at $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$, however, deserve further discussion. We start with the observation that, for $\hbar\omega_{pump} = 3.1\text{eV}$, the population dynamics in the WS_2 CB in Fig. 2c2 are different at K and close to Q. The 3.1eV pump pulse directly populates states close to the Q valley (see Fig. 1a). These carriers are then observed to scatter to the K valley within $\sim 130\text{fs}$ (see Fig. 2c2) in good agreement with previously reported intervalley scattering times for WS_2 and similar TMDCs [30–34].

Next, we focus on the observation that the gain above the equilibrium position of the WS_2 VB (Fig. 2b) and the charging shifts in Fig. 3c and d are found to reach their extrema at earlier time delays for $\hbar\omega_{pump} = 3.1\text{eV}$ than for $\hbar\omega_{pump} = 2.0\text{eV}$. This indicates that hole transfer is faster for $\hbar\omega_{pump} = 3.1\text{eV}$ than for $\hbar\omega_{pump} = 2.0\text{eV}$. From [18] it is known that the rates for charge transfer from WS_2 to graphene increase with increasing electronic temperature as it becomes easier for the photoexcited carriers to overcome the energy barriers to possible charge transfer states. The transient electronic temperatures for the WS_2 layer are difficult to determine due to the small population of the WS_2 CB and the limited signal-to-noise ratio. The transient electronic temperature of the carriers inside the Dirac cone of graphene, however, can be extracted by fitting its transient population with a Fermi-Dirac distribution. The resulting electronic temperature is displayed in Fig. 4. We find that, despite differences in excitation energy and pump fluence, the transient electronic temperatures for $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$ are very similar. Therefore, we conclude that differences in electronic temperature cannot account for the observation that hole transfer is faster for $\hbar\omega_{pump} = 3.1\text{eV}$.

Instead, we propose that the different hole transfer rates for $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$ can be attributed to different tunneling pathways via different charge transfer states in the WS_2 VB. These charge transfer states have been previously identified using density functional theory calculations [13]. For convenience, we sketch the relevant part of the band structure of the WS_2 -graphene heterostructure in Fig. 5. Charge transfer states, where the WS_2 and graphene bands hybridize, are shown in red. For $\hbar\omega_{pump} = 2.0\text{eV}$, photoexcitation occurs at the K valley of WS_2 . The previously proposed scattering processes resulting in ultrafast charge transfer to the graphene layer are indicated by orange arrows [18, 13]. For $\hbar\omega_{pump} = 2.0\text{eV}$, hole transfer is believed to occur via the charge transfer state located at $k > K$ in the WS_2 VB. Electrons likely transfer into the graphene layer via the charge transfer state located at $Q < k < K$ in the CB. For 3.1eV excitation, electron-hole pairs are initially generated at momenta between Γ and Q. We propose that, on their way towards the VB maximum at K, these holes pass by the charge transfer state at $Q < k < K$ in the VB where they efficiently transfer into the graphene layer (blue arrows in Fig. 5). The reason why hole transfer at $Q < k < K$ is faster than at $k > K$ is that the size of the avoided crossing between WS_2 VB and graphene Dirac cone is bigger (and therefore hybridization is stronger) at $Q < k < K$ than at $k > K$ [13]. The charge transfer state for electrons inside the WS_2 CB is likely the same for $\hbar\omega_{pump} = 2.0\text{eV}$ and $\hbar\omega_{pump} = 3.1\text{eV}$ consistent with similar population lifetimes in Table 1 as well as similar decay times for the charging shifts in Table 2.

Summary and Outlook

In summary, we used trARPES of a WS_2 -graphene heterostructure to show that electron-hole pairs positioned at different momenta in the Brillouin zone of WS_2 choose different quantum pathways to transfer into the vdW-coupled graphene layer. These results show that charge separation across vdW interfaces can be controlled via the incident pump photon energy, opening up new strategies to optimize the performance of vdW heterostructures for future applications in light harvesting and detection.

Materials and Methods

Sample growth: Pretreated 4H-SiC substrates were H-etched to remove scratches and graphitized in Ar atmosphere. The resulting carbon monolayer with $(6\sqrt{3} \times 6\sqrt{3})R30^\circ$ structure was decoupled from the SiC substrate by H-intercalation, yielding quasi-freestanding monolayer graphene [35]. WS₂ was then grown by chemical vapour deposition (CVD) from solid WO₃ and S precursors [36, 37]. Both graphene and WS₂ growth were monitored using Raman spectroscopy, atomic force microscopy and secondary electron microscopy. WS₂ was found to grow in the shape of triangular islands with side lengths in the range of 300 – 700nm with twist angles of either 0° or 30° with respect to the graphene layer [13].

trARPES: The setup was based on a Ti:Sa amplifier (Astrella, Coherent) with 1kHz repetition rate, 35fs pulse duration, 1.55eV photon energy, and 7mJ output power. Of this, 2mJ were frequency-doubled and used to drive high harmonics generation (HHG) in an Argon gas jet. The 7th harmonic at 21.7eV was isolated using a grating monochromator and focused onto the sample with a beam diameter of 250 μ m. A small part of the 2mJ output was frequency doubled to generate pump pulses with a photon energy of 3.1eV with a fluence of 0.4mJ/cm² at the focus. The remaining 5mJ seeded an optical parametric amplifier (Topas Twins, Light Conversion). One of the signal beams was frequency doubled to generate pump pulses with a photon energy of 2.0eV with a fluence of 1.7mJ/cm² at the focus. The photoemitted electrons were detected with a hemispherical analyzer (Phoibos 100, SPECS) to obtain snapshots of the occupied band structure along the Γ K direction of graphene. The temporal and energy resolutions were \sim 200meV and \sim 160fs, respectively.

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trARPES experiments and data analysis: NH, LW

data interpretation: NH, JG, LW, IG

Supervision: CC, IG

Writing—original draft: NH, IG

Writing—review & editing: NH, JG, LW, SF, CC, IG

Competing interests: Authors declare that they have no competing interests.

Data and materials availability: All data will be made available upon reasonable request to the corresponding author.

Figures and Tables

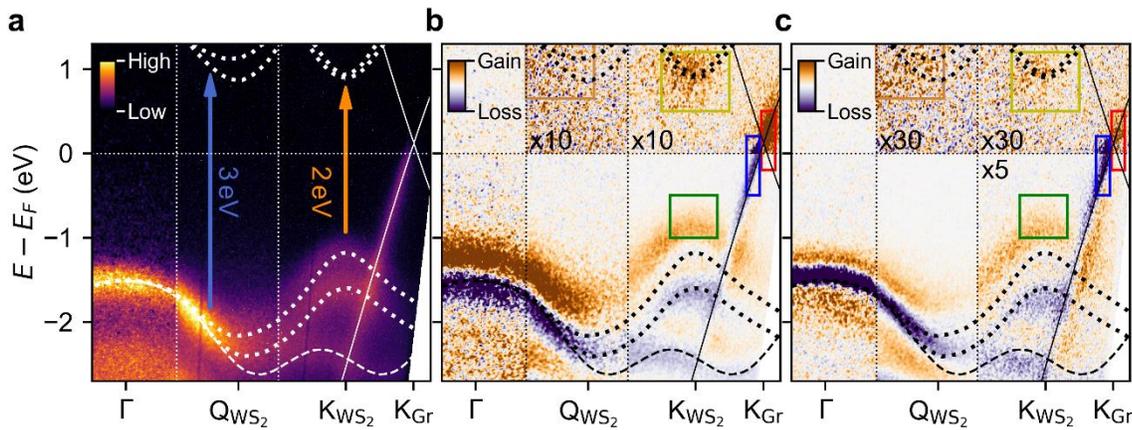


Figure 1 | trARPES data of WS₂-graphene heterostructure. a) ARPES snapshots for negative pump-probe delay taken along the ΓK direction of graphene. Orange and blue arrows indicate the two different excitation schemes for $\hbar\omega_{pump} = 2.0eV$ and $\hbar\omega_{pump} = 3.1eV$, respectively. Dotted, dashed and continuous lines represent the theoretical band structures for WS₂ with twist angles of 0° and 30° [20] and graphene [21], respectively. b) Pump-induced changes of the photocurrent in a) 240fs after excitation with $\hbar\omega_{pump} = 2.0eV$. c) Same as b) but 310fs after excitation with $\hbar\omega_{pump} = 3.1eV$. Colored boxes in b) and c) mark the regions of integration for the pump-probe traces displayed in Fig. 2.

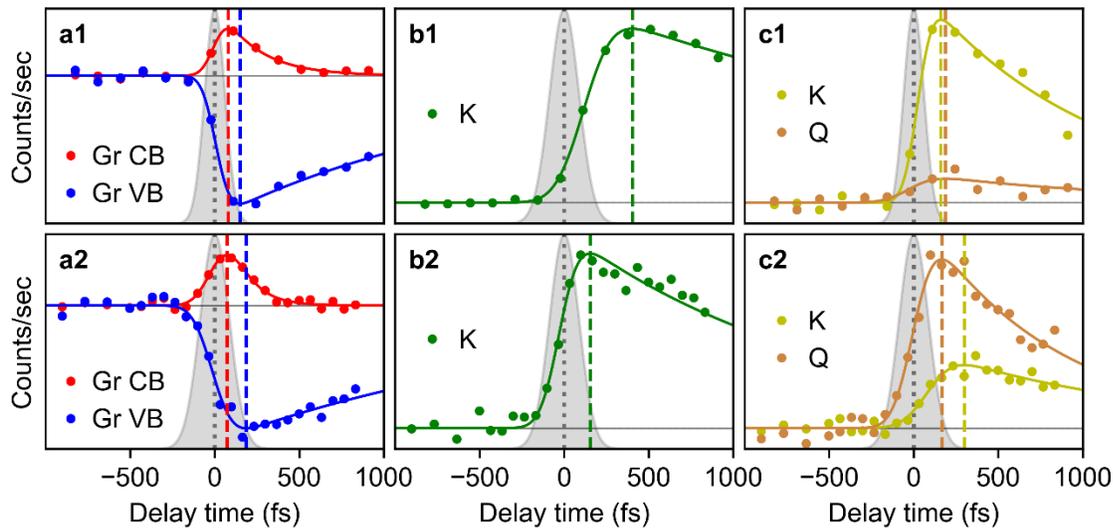


Figure 2 | Population dynamics obtained by integrating the counts over the areas marked by colored boxes in Figs. 1b and d. a) Gain (red) and loss (blue) inside the Dirac cone. b) Gain above the equilibrium position of the WS₂ VB at K. c) Population of the WS₂ CB at K (yellow) and close to Q (orange). Rows 1 and 2 present data for excitation at $\hbar\omega_{pump} = 2.0eV$ and $\hbar\omega_{pump} = 3.1eV$, respectively. Continuous lines are single-exponential fits. Dashed colored lines indicate the pump-probe delay where the pump-probe traces reach their maximum. Grey-shaded areas indicate the temporal profile of the pump pulse.

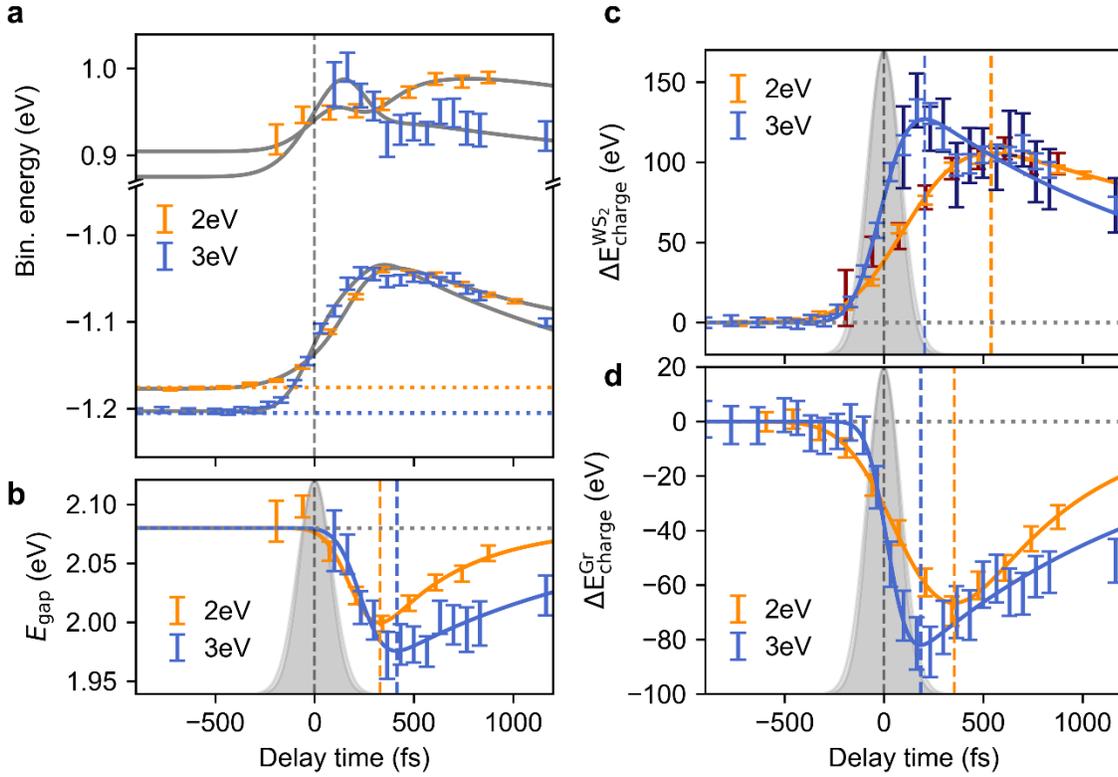


Figure 3 | Transient band structure. **a)** Transient band position of WS₂ CB (top) and VB (bottom). **b)** Transient band gap. **c)** Charging shifts of WS₂ VB and CB. **d)** Charging shift of Dirac cone. Data points for excitation at $\hbar\omega_{pump} = 2.0eV$ and $\hbar\omega_{pump} = 3.1eV$ are shown in orange and blue, respectively. Orange and blue curves are single-exponential fits. Grey curves in a) are guides to the eye calculated from the VB fit in a) and the gap fit in b) for the CB, and from the gap fit in b) and the charging shift fit in c) for the VB. Vertical colored dashed lines indicate the pump-probe delay where the pump-probe traces reach their maximum. Grey-shaded areas indicate the temporal profiles of the pump pulses.

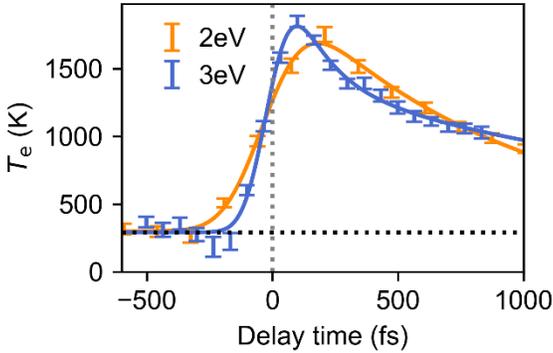


Figure 4 | Transient electronic temperature inside the Dirac cone obtained by fitting the transient carrier population of the Dirac cone with a Fermi-Dirac distribution. Data points for excitation at $\hbar\omega_{pump} = 2.0eV$ and $\hbar\omega_{pump} = 3.1eV$ are shown in orange and blue, respectively. Orange and blue lines are double-exponential fits that serve as guides to the eye.

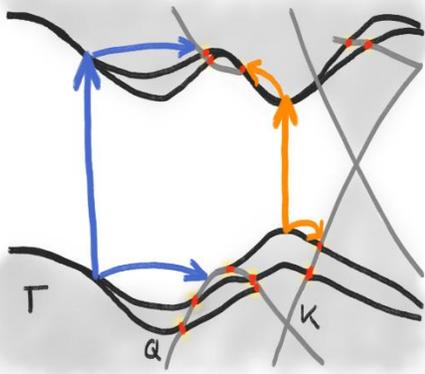


Figure 5 | Schematic of quantum pathways for ultrafast charge transfer. The band structure sketch is based on density functional theory calculations from [13]. The color code indicates whether the wave function is localized on the graphene layer (gray curves), the WS₂ layer (black curves) or delocalized over both layers (red dots). Blue (orange) arrows indicate direct optical transitions excited at $\hbar\omega_{pump} = 3.1eV$ ($\hbar\omega_{pump} = 2.0eV$) and subsequent carrier relaxation via different charge transfer states.

Table 1 | Fit parameters for single-exponential fits of pump-probe traces shown in Fig. 2.

	Red box	Blue box	Green box	Orange box	Yellow box
	Graphene gain	Graphene loss	Gain above equilibrium position of WS ₂ VB	Gain in WS ₂ CB at K	Gain in WS ₂ CB close to Q
$\tau_{2.0eV}$	$230 \pm 40fs$	$1.7 \pm 0.2ps$	$3.2 \pm 0.4ps$	$1.0 \pm 0.1ps$	$1.3 \pm 0.8ps$
$\tau_{3.1eV}$	$120 \pm 30fs$	$2.2 \pm 0.2ps$	$1.5 \pm 0.1ps$	$1.3 \pm 0.2ps$	$0.8 \pm 0.1ps$
$t_{max,2.0eV}$	$\sim 80fs$	$\sim 150fs$	$\sim 400fs$	$\sim 160fs$	$\sim 190fs$
$t_{max,3.1eV}$	$\sim 70fs$	$\sim 190fs$	$\sim 160fs$	$\sim 300fs$	$\sim 170fs$

Table 2 | Fit parameters for single-exponential fits of pump-probe traces shown in Fig. 3.

	WS ₂ VB position	E_{gap}	$\Delta E_{charge}^{WS_2}$	ΔE_{charge}^{Gr}
$\tau_{2.0eV}$	$1.5 \pm 0.2ps$	$0.4 \pm 0.2ps$	$2.7 \pm 0.9ps$	$0.6 \pm 0.1ps$
Amplitude _{2.0eV}	$137 \pm 6meV$	$80 \pm 30meV$	$110 \pm 10meV$	$70 \pm 10meV$
$\tau_{3.1eV}$	$1.3 \pm 0.1ps$	$1.2 \pm 0.2fs$	$1.5 \pm 0.2fs$	$1.3 \pm 0.1fs$
Amplitude _{3.1eV}	$169 \pm 8meV$	$104 \pm 8meV$	$127 \pm 6meV$	$82 \pm 3meV$
$t_{max,2.0eV}$	$\sim 350fs$	$\sim 330fs$	$\sim 540fs$	$\sim 350fs$
$t_{max,3.1eV}$	$\sim 400fs$	$\sim 410fs$	$\sim 200fs$	$\sim 190fs$